



A Product Line of Diodes Incorporated



ZXT1053AK

75V NPN LOW SATURATION MEDIUM POWER TRANSISTOR

Features

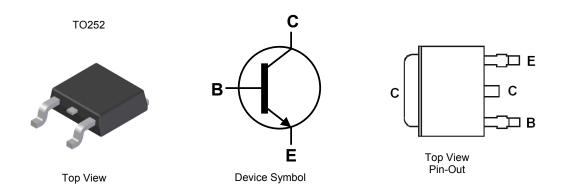
- BV_{CEO} > 75V
- I_C = 5A high Continuous Collector Current
- Up to 10A Peak Current
- R_{SAT} = 70mΩ for a low equivalent On-Resistance
- Low Saturation Voltage
- h_{FE} specified up to 10A for a high gain hold up
- Lead-Free Finish; RoHS compliant (Note 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP capable (Note 4)

Mechanical Data

- Case: TO252 (DPAK)
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.34 grams (approximate)

Application

- DC DC converters
- Power Switches
- Motor Control
- Automotive Circuits
- Inverter Circuits



Ordering Information (Notes 4 & 5)

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Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXT1053AKTC	AEC-Q101	ZXT1053A	13	16	2,500
ZXT1053AKQTC	Automotive	ZXT1053A	13	16	2,500

Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

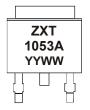
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q10x qualified and are PPAP capable. Automotive, AEC-Q10x and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html

Marking Information



ZXT1053AK = Product Type Marking Code YYWW = Date Code Marking YY = Last Digit of Year (ex: 09 = 2009) WW = Week Code (01 – 53)





ZXT1053AK

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	150	V
Collector-Emitter Voltage	V _{CEO}	75	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	Ic	5	A
Peak Pulse Collector Current	I _{CM}	10	А

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
	(Note 6)		2.1	
Power Dissipation	(Note 7)	PD	3.4	W
	(Note 8)		4.0	
	(Note 6)		59	
Thermal Resistance, Junction to Ambient Air	(Note 7)	R _{0JA}	36	°C/W
	(Note 8)		32	
Thermal Resistance, Junction to Leads (Note 9)		R _{θJL}	2.97	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	۵°	

ESD Ratings (Note 10)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

6. For a device mounted with the exposed collector pad on 25mm x 25mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
7. Same as note (6), except the device is surface mounted on 25mm x 25mm with 2oz copper. Notes:

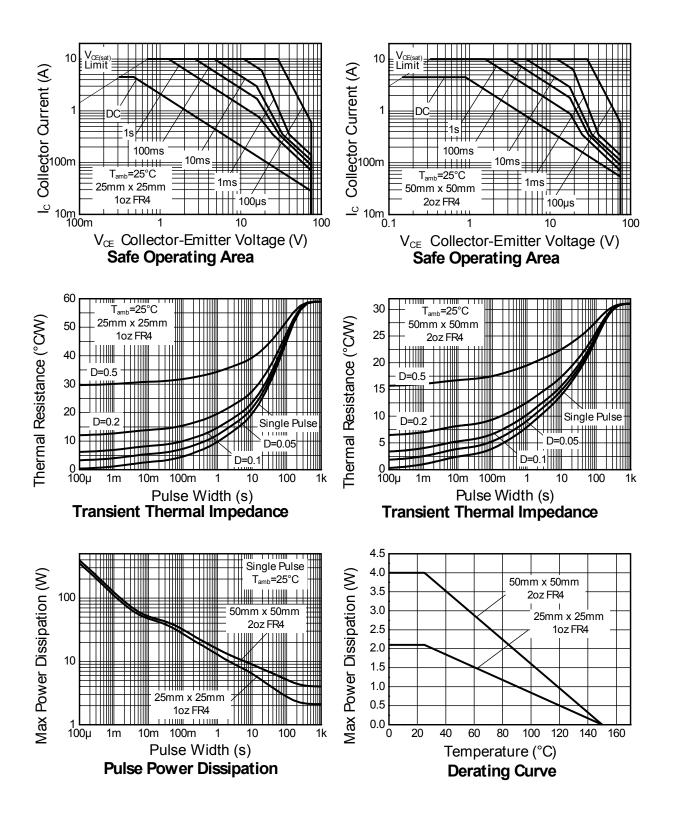
8. Same as note (6), except the device is surface mounted on 50mm x 50mm with 2oz copper.

Thermal resistance from junction to solder-point (at the end of the collector lead).
 Refer to JEDEC specification JESD22-A114 and JESD22-A115.





Thermal Characteristics and Derating Information







Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

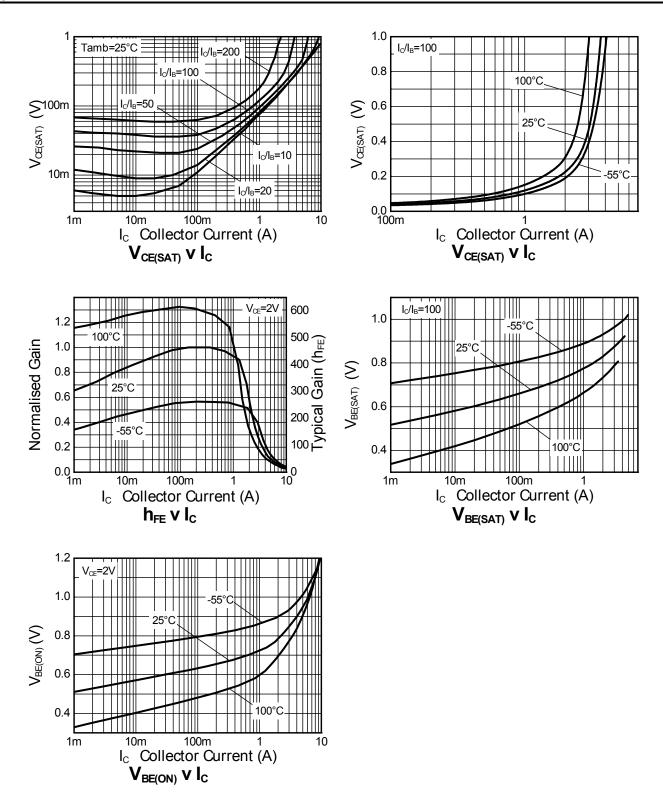
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Characteristic	Symbol	Min	Тур.	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	150	240	—	V	I _C = 100μA
Collector-Base Breakdown Voltage	BV _{CES}	150	240		V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 11)	BV _{CEO}	75	90	-	V	I _C = 10mA
Collector-Emitter Breakdown Voltage	BV _{CEV}	150	240		V	I _C = 1μΑ, V _{EB} = 1V
Emitter-Base Breakdown Voltage	BV _{EBO}	7	8.7		V	I _E = 100μA
Collector Cutoff Current	I _{CBO}	-	<1	10	nA	V _{CB} = 120V
Emitter Cutoff Current	I _{EBO}	_	<1	10	nA	V _{EB} = 6V
Emitter Cutoff Current	ICES	-	<1	10	nA	V _{CE} = 120V
DC current transfer Static ratio (Note 9)	h _{FE}	260 300 50 10	375 450 75 25	1200 —	_	$I_{C} = 10mA, V_{CE} = 2V$ $I_{C} = 1A, V_{CE} = 2V$ $I_{C} = 5A, V_{CE} = 2V$ $I_{C} = 10A, V_{CE} = 2V$
Collector-Emitter Saturation Voltage (Note 11)	V _{CE(sat)}	 	19 70 120 140 350	30 95 160 190 460	mV	$\begin{split} I_{C} &= 0.2A, \ I_{B} = 20 mA \\ I_{C} &= 1A, \ I_{B} = 100 mA \\ I_{C} &= 1A, \ I_{B} = 10 mA \\ I_{C} &= 2A, \ I_{B} = 100 mA \\ I_{C} &= 5A, \ I_{B} = 200 mA \end{split}$
Base-Emitter Saturation Voltage (Note 11)	V _{BE(sat)}	-	1.0	1.1	V	I _C = 5A, I _B = 200mA
Base-Emitter Turn-on Voltage (Note 11)	V _{BE(on)}	-	0.925	1.05	V	I _C = 5A, V _{CE} = 2V
Transitional Frequency	f _T	_	140	_	MHz	I _C = 50mA, V _{CE} = 10V f = 100MHz
Output capacitance	Сово	—	21	30	pF	V _{CB} = 10V, f = 1MHz,
Switching times	t _{ON} toff	_	162 900	_	nS	$I_{C} = 2A, V_{CC} = 50V,$ $I_{B1} = I_{B2} = 20mA$

Notes: 11. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.





Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

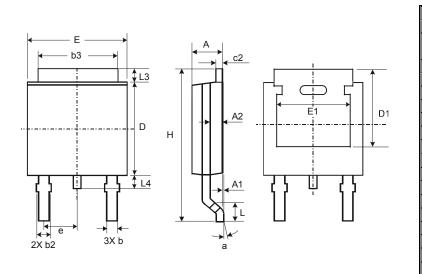






Package Outline Dimensions

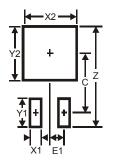
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



TO252					
Dim	Min	Max	Тур		
Α	2.19	2.39	2.29		
A1	0.00	0.13	0.08		
A2	0.97	1.17	1.07		
b	0.64	0.88	0.783		
b2	0.76	1.14	0.95		
b3	5.21	5.46	5.33		
c2	0.45	0.58	0.531		
D	6.00	6.20	6.10		
D1	5.21	-	-		
е	-	_	2.286		
Ε	6.45	6.70	6.58		
E1	4.32	_	-		
Н	9.40	10.41	9.91		
L	1.40	1.78	1.59		
L3	0.88	1.27	1.08		
L4	0.64	1.02	0.83		
а	0°	10°	-		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	11.6
X1	1.5
X2	7.0
Y1	2.5
Y2	7.0
С	6.9
E1	2.3





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